100V 2.2A N-Channel Enhancement Mode Power MOSFET

General Description

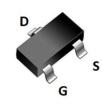
This Power MOSFET has been developed using advanced trench process, which is specifically designed to minimize input capacitance and gate charge. This renders the device suitable for use as primary switch in advanced high-efficiency isolated DC-DC converters for telecom and computer applications, and applications with low gate charge driving requirements.

FEATURES

- RDSON \leq 280m Ω @Vgs=10V, Id=2A
- Excellent RDS(ON) and Low Gate Charge
- · Lead free product is acquired

SYMBOL





SOT-23 top view

ASSEMBLY MESSAGE

Product Name	Marking	Package	Packaging
BXT2800N10M	0102	SOT-23	Reel

ABSOLUTE MAXIMUM RATINGS (Tc=25°C unless otherwise noted)

Parameter		Symbol	Rating	Unit	
			SOT-23		
Drain-Source Voltage	Drain-Source Voltage		V _{DSS}	100	V
Drain Current	Con	tinuous (T _C = 25°C)	I.	2.2	А
Drain Current	Con	tinuous (T _C = 100°C)	lo	1.4	А
Drain Current Pulsed (Note1)		I _{DM}	8.8	А	
Gate-Source Voltage		V _{GSS}	±20	V	
Power Dissipation T _C =25°C		PD	2.8	W	
Maximum Junction Temperature		TJ	150	°C	
Storage Temperature Range		Tstg	-55 to 150	°C	

Note: 1. Repetitive Rating: Pulse width limited by maximum junction temperature



BXT2800N10M

THERMAL CHARACTERISTICS

	Parameter	Symbol	Max.	Unit	
	Farameter	Symbol	SOT-23		
Thermal Resistance, Junction-to- Ambient		Reja	44	°C / W	

ELECTRICAL CHARACTERISTICS (T_J=25°C, unless otherwise Noted)

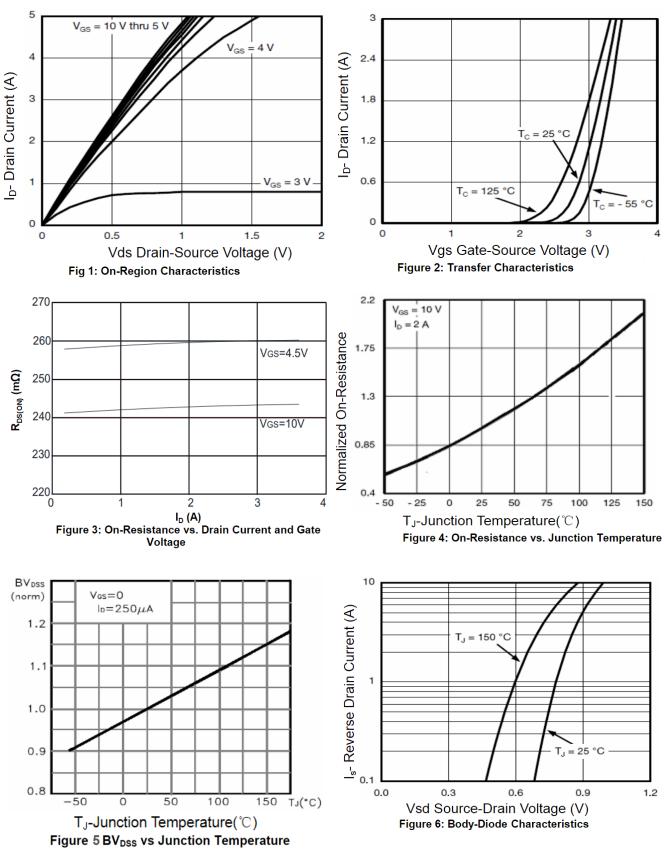
Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Unit
OFF CHARACTERISTICS				•		
Drain-Source Breakdown Voltage	BV _{DSS}	VGS=0V, ID=250µA	100			V
Zero Gate Voltage Drain Current	IDSS	VDS=100V, VGS=0V			1	uA
Gate-Body Leakage Current, Forward		VGS=20V			100	nA
Gate-Body Leakage Current, Reverse	I _{GSS}	VGS=-20V			-100	nA
ON CHARACTERISTICS			•	•		
Gate Threshold Voltage	V _{GS(TH)}	VDS=VGS, ID=250µA	1.0	2.1	3.0	V
Drain-Source On-State Resistance	Deserve	VGS=10V, ID=2A		243	280	mΩ
Drain-Source On-State Resistance	Rds(ON)	VGS=4.5V, ID=1A		259	310	mΩ
DYNAMIC PARAMETERS						
Input Capacitance	Ciss	VDS=50V, VGS=0V, f=1.0MHz		360		pF
Output Capacitance	Coss			24		pF
Reverse Transfer Capacitance	Crss			13		pF
SWITCHING PARAMETERS						
Turn-ON Delay Time	t _{D(ON)}			14		ns
Turn-ON Rise Time	t _R	VDD=50V, ID=1A, VGS =		54		ns
Turn-OFF Delay Time	t _{D(OFF)}	10V, RG=3Ω		18		ns
Turn-OFF Fall-Time	t _F			11		ns
Total Gate Charge(Note2)	Q _G			12		nC
Gate Source Charge	Q _{GS}	VDS =50V, VGS =10V, ID =2A		1.8		nC
Gate Drain Charge	Q _{GD}			2.9		nC
SOURCE- DRAIN DIODE RATINGS		ACTERISTICS				
Drain-Source Diode Forward Voltage	V _{SD}	IS=2.2A, VGS=0V			1.2	V
Diode Continuous Forward Current	ls				2.2	Α

Note: 2. Essentially independent of operating temperature



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TYPICAL CHARACTERISTICS





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TYPICAL CHARACTERISTICS(Cont.)

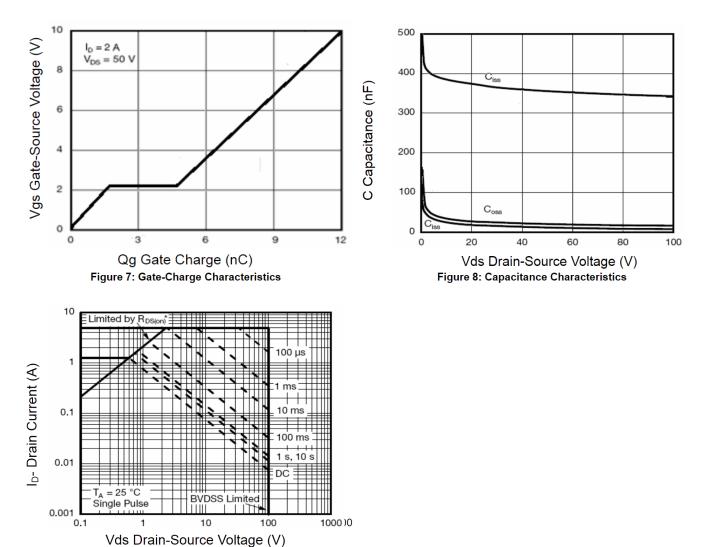
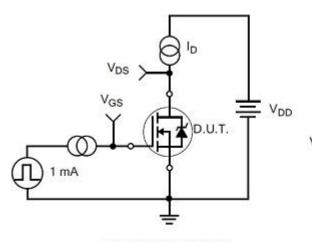


Figure 9: Maximum Forward Biased Safe Operating Area

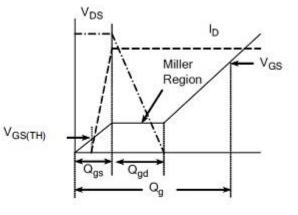


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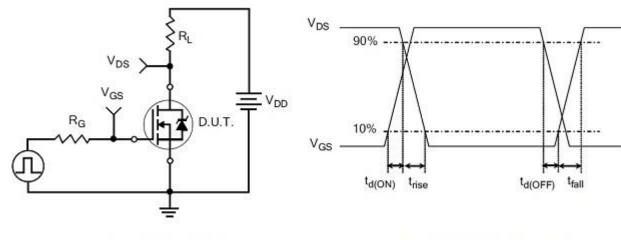
TEST CIRCUITS AND WAVEFORMS



Gate Charge Test Circuit



Gate Charge Waveform

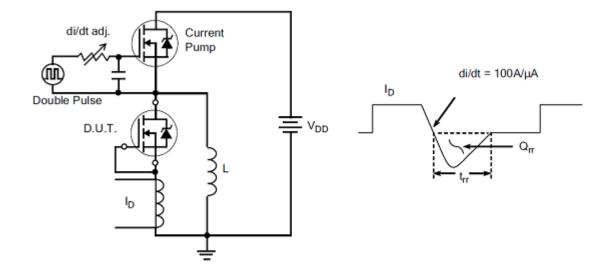


Resistive Switching Test Circuit

Resistive Switching Waveforms

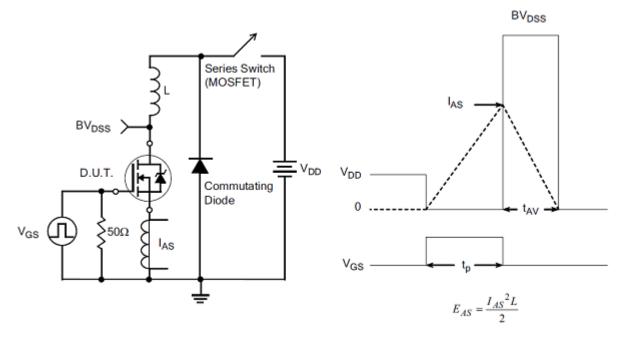


TEST CIRCUITS AND WAVEFORMS(Cont.)



Diode Reverse Recovery Test Circuit

Diode Reverse Recovery Waveform

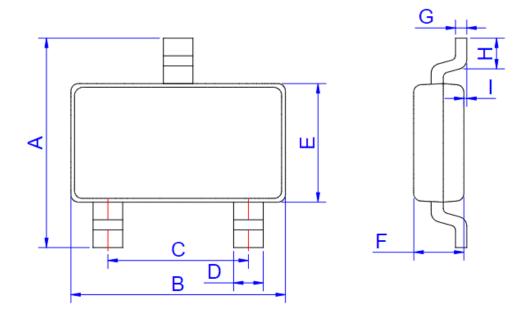


Unclamped Inductive Switching Test Circuit

Unclamped Inductive Switching Waveforms



SOT-23 Package



SOT-23

	Dimensions					
Ref.	Millimeters		Inches			
	Min.	Max.	Min.	Max.		
А	2.250	2.550	0.089	0.100		
В	2.800	3.000	0.110	0.118		
С	1.800	2.000	0.071	0.079		
D	0.300	0.500	0.012	0.020		
E	1.200	1.400	0.047	0.055		
F	0.900	1.150	0.035	0.045		
G		0.200		0.008		
Н	0.200		0.008			
I	0.000	0.150	0.000	0.006		



Revision history

Document revision history

Date	Revision	Changes
28-Oct-2020	1.0	First release

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BXT2800N10M

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